

# RF Low Noise FET CE3521M4

# 20 GHz Low Noise FET in Dual Mold Plastic PKG

#### DESCRIPTION

- Low Noise and High Gain
- Original Dual Mold Plastic package

#### **FEATURES**

• Low noise figure and high associated gain: NF = 0.70 dB TYP., Ga = 11.9 dB TYP.  $@V_{DS} = 2 V$ , I<sub>D</sub> = 10 mA, f = 20 GHz

### PACKAGE

• Flat-lead 4-pin thin-type super minimold package



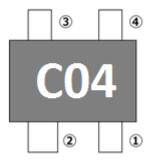
#### **APPLICATIONS**

- DBS LNB gain-stage, Mix-stage
- Low noise amplifier for microwave communication systems

### **ORDERING INFORMATION**

Part Number	Order Number	Package	Marking	Description
CE3521M4	CE3521M4-C2	Flat-lead 4-pin	C04	<ul> <li>Embossed tape 8 mm wide</li> </ul>
		thin-type super		Pin 1 (source), Pin 2 (drain)
		minimold		face the perforation side of
		package		the tape
				MOQ 15 kpcs/reel

### PIN CONFIGURATION AND INTERNAL BLOCK DIAGRAM



Pin No.	Pin Name
1	Source
2	Drain
3	Source
4	Gate

### **ABSOLUTE MAXIMUM RATINGS**

#### $(TA = +25^{\circ}C, unless otherwise specified)$

Parameter	Symbol	Rating	Unit
Drain to Source Voltage	V <sub>DS</sub>	4.0	V
Gate to Source Voltage	V <sub>GS</sub>	-3.0	V
Drain Current	Ι <sub>D</sub>	I <sub>DSS</sub>	mA
Gate Current	l <sub>G</sub>	80	μA
Total Power Dissipation	P <sub>tot</sub>	125	mW
Channel Temperature	T <sub>ch</sub>	+150	°C
Storage Temperature	T <sub>stg</sub>	-55 to +125	°C
Operation Temperature	T <sub>op</sub>	-55 to +125 <sup>Note</sup>	°C

Note Refer to Total Power Dissipation vs. Ambient Temperature graph on page 4

### **RECOMMENDED OPERATING RANGE**

(TA = +25°C, unless otherwise specified) Parameter Symbol MIN. TYP. MAX. Unit Drain to Source Voltage V  $V_{\text{DS}}$ +1 +2 +3 **Drain Current** 5 10 15 mΑ  $I_{D}$ 

#### This document is subject to change without notice.

### **ELECTRICAL CHARACTERISTICS**

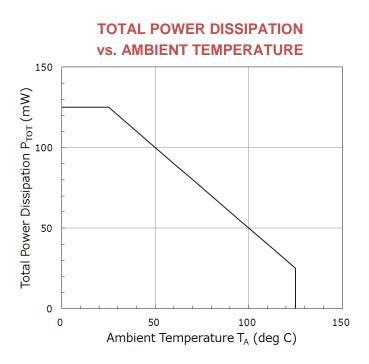
#### $(TA = +25^{\circ}C, unless otherwise specified)$

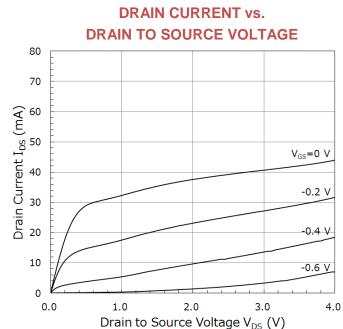
Parameter	Symbol	Condition	MIN.	TYP.	MAX.	Unit
Gate to Source Leak Current	I <sub>GSO</sub>	V <sub>GS</sub> = -3.0V	-	0.4	10	μA
Saturated Drain Current	I <sub>DSS</sub>	$V_{DS} = 2V, V_{GS} = 0V$	23	40	57	mA
Gate to Source Cut-off Voltage	V <sub>GS(off)</sub>	$V_{DS} = 2V, I_{D} = 100 \mu A$	-1.10	-0.75	-0.39	V
Transconductance	Gm	$V_{DS} = 2V, I_{D} = 10mA$	47	62	-	mS
Noise Figure	NF	$V_{DS} = 2V, I_{D} = 10mA,$	-	0.70	1.05	dB
Associated Gain	Ga	f = 20GHz	9.9	11.9	-	dB



#### **TYPICAL CHARACTERISTICS** :

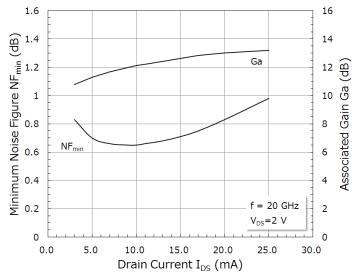
(TA=+25℃, unless otherwise specified)





DRAIN CURRENT vs. GATE TO SOURCE VOLTAGE

MINIMUM NOISE FIGURE & ASSOCIATED GAIN vs. DRAIN CURRENT





#### **S-PARAMETERS**

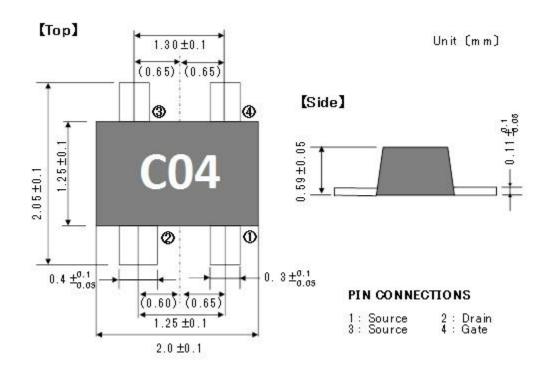
S-Parameters are available on the CEL web site.

#### **RECOMMENDED SOLDERING CONDITIONS**

Recommended Soldering Conditions are provided on the CEL web site.

#### PACKAGE DIMENSIONS

Flat-lead 4-pin thin-type super minimold package



### **REVISION HISTORY**

Version	Change to current version	Page(s)
CDS-0020-03 (Issue A)	Initial datasheet	N/A
February 19, 2016		
CDS-0020-03 (Issue B)	Updated Marking Information	1, 2, 3
April 27, 2016		
CDS-0020-04 (Issue A)	Updated Specs in "Absolute Maximum Ratings" Table	2, 4, 5
July 29, 2016	Added "Typical Characteristics" section (graphs)	
-	Added "S-Parameters" and "Recommended Soldering	
	Conditions" sections	



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